

Product Summary

Symbol	Value	Unit
$I_{T(RMS)}$	1.0	A
$V_{DRM} V_{RRM}$	600/800	V
V_{TM}	1.55	V

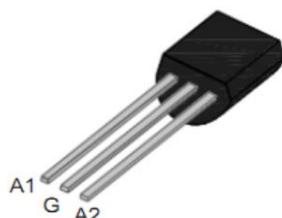
Feature

With high ability to withstand the shock loading of large current, With high commutation performances, 4 quadrants products especially recommended for use on inductive load.

Application

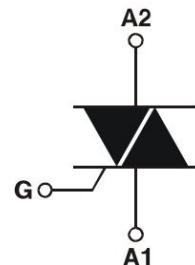
Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

Package

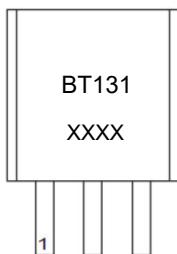


TO-92

Circuit diagram



Marking



Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value		Unit
Repetitive peak off-state voltage	V _{DRM}	600/800		V
Repetitive peak reverse voltage	V _{RRM}	600/800		V
RMS on-state current	I _{T(RMS)}	1		A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I _{TSM}	16		A
I ² t value for fusing (tp=10ms)	I ² t	1.28		A ² s
Critical rate of rise of on-state current (I _G =2×I _{GT})	dI/dt	I - II - III IV	50 10	A/μs
Peak gate current	I _{GM}	2		A
Average gate power dissipation	P _{G(AV)}	0.5		W
Junction Temperature	T _J	-40 ~ +125		°C
Storage Temperature	T _{STG}	-40 ~ +150		°C

Electrical characteristics (T_A=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition		Value		Unit
Gate trigger current	I _{GT}	V _D =12V I _T =0.1A T _j =25°C	I - II - III	MAX.	5	mA
Gate trigger voltage	V _{GT}		IV		10	
Gate non-trigger voltage	V _{GD}	V _D =V _{DRM} T _j =125°C		MIN.	0.2	V
latching current	I _L	V _D =12V I _{GT} =0.1A T _j =25°C	I - III - IV	MAX.	10	mA
			II		15	
			I - II - III - IV	MAX.	5	
Critical-rate of rise of commutation voltage	dV/dt	V _D =2/3V _{DRM} Gate Open T _j =125°C		MIN.	50	V/μs
STATIC CHARACTERISTICS						
Forward "on" voltage	V _{TM}	I _{TM} =1.5A tp=380μs		MAX.	1.55	V
Repetitive Peak Off-State Current	I _{DRM}	V _D =V _{DRM} V _R =V _{RRM}	T _j =25°C	MAX.	5	μA
Repetitive Peak Reverse Current	I _{RRM}		T _j =125°C	MAX.	100	μA
THERMAL RESISTANCES						
Thermal resistance	R _{th(j-c)}	Junction to case(AC)		TYP.	60	°C/W
	R _{th(j-a)}	Junction to ambient		TYP.	150	°C/W

Typical Characteristics

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

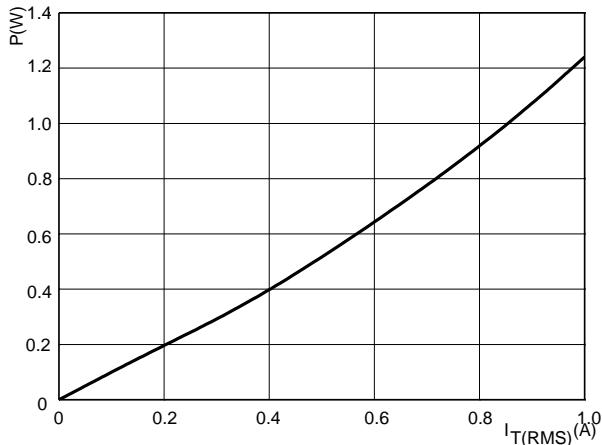


FIG.2: RMS on-state current versus case temperature (full cycle)

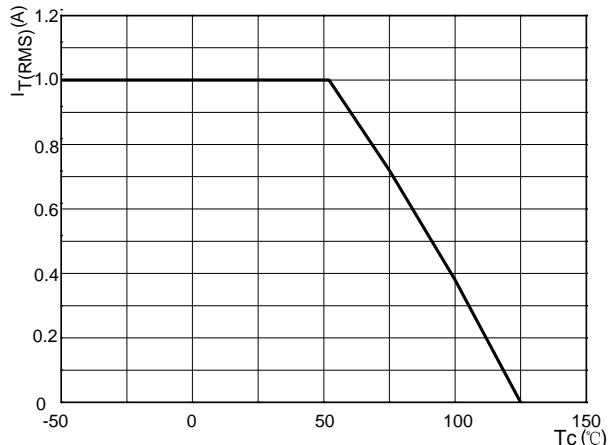


FIG.3: Surge peak on-state current versus number of cycles

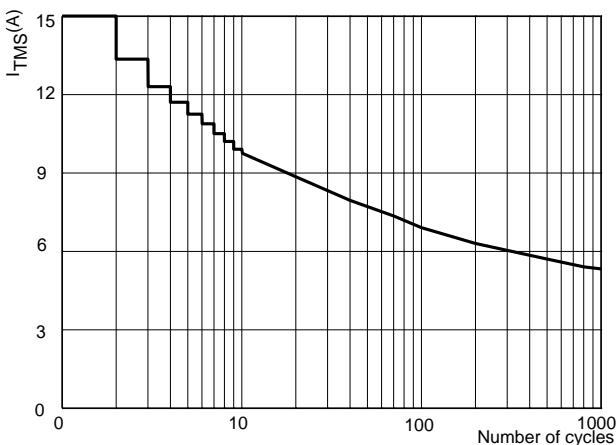


FIG.4: On-state characteristics (maximum values)

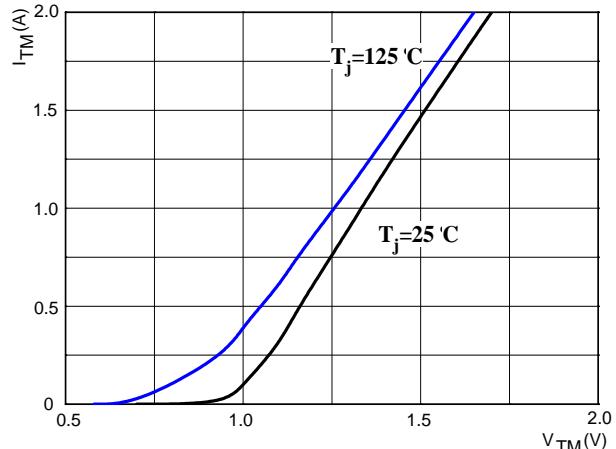


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$

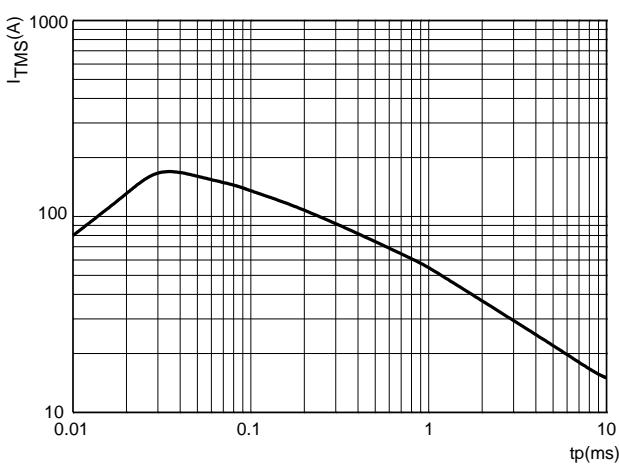
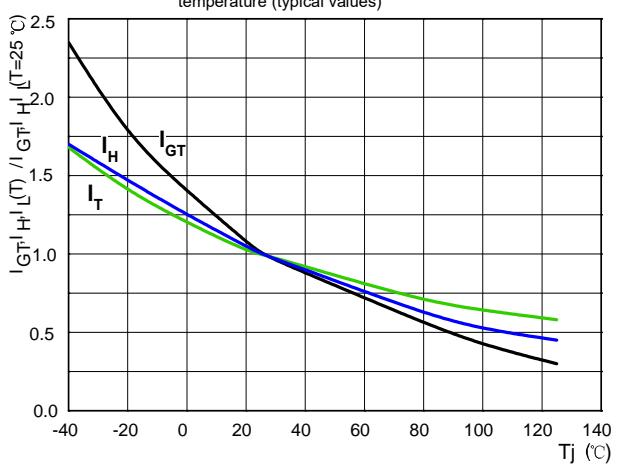
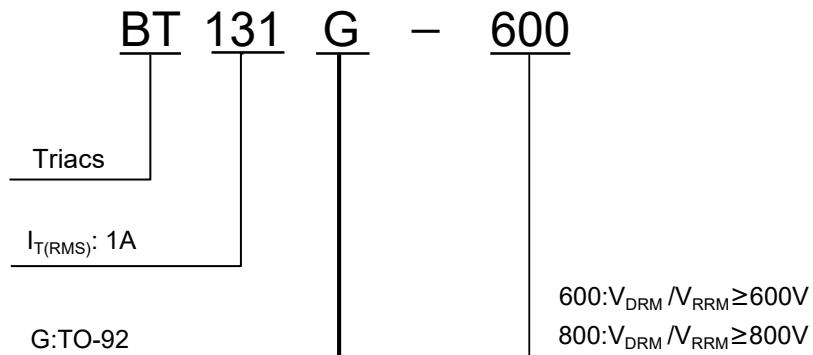


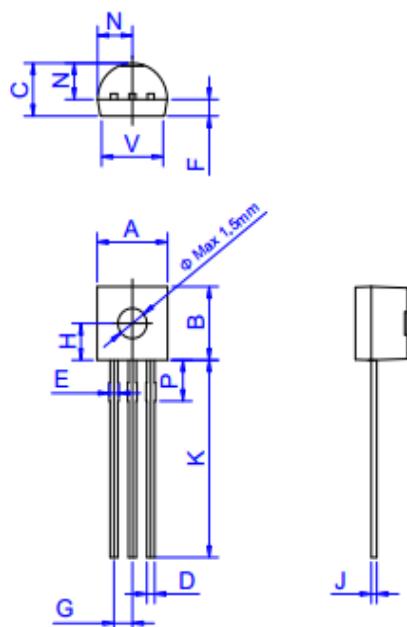
FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



Ordering Information



TO-92 Package Information



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.45		5.20	0.175		0.205
B	4.32		5.33	0.170		0.210
C	3.18		4.19	0.125		0.165
D	0.407		0.533	0.016		0.021
E	0.60		0.80	0.024		0.031
F	-	1.1	-	-	0.043	-
G	-	1.27	-	-	0.050	-
H	-	2.30	-	-	0.091	-
J	0.36		0.50	0.014		0.020
K	12.70		15.0	0.500		0.591
N	2.04		2.66	0.080		0.105
P	1.86		2.06	0.073		0.081
V	-		4.3	-		0.169